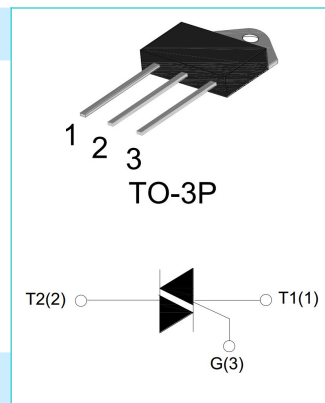


Standard TRIACS

BTA41 Serial

Main Features:

$I_{T(RMS)}$	V_{DRM}/V_{RRM}	V_{TM}
40 A	600/800/1200/1600 V	≤ 1.5 V



Description:

High current density due to double mesa technology; Glass Passivation. BTA41 series TRIACS is suitable for general purpose AC switching. They can be used as an ON/OFF Function in applications such as static relays, heating regulation, induction motor starting circuits, or for phase control operation light dimmers, motor speed controllers.

Absolute Ratings(limiting values) :

Symbol	Parameter		Value	Unit
T_{stg}	Storage junction temperature range		- 40 to + 150	$^{\circ}\text{C}$
T_j	Operating junction temperature range		- 40 to + 125	$^{\circ}\text{C}$
$I_{T(RMS)}$	RMS on-state current	TO-3P(Ins) (TC=80 $^{\circ}\text{C}$)	40	A
I_{TSM}	Non repetitive surge peak on-state current (tp=10ms)		400	A
V_{DRM}	Repetitive peak off-state voltage(Tj =25 $^{\circ}\text{C}$)		600/800/1200/1600	V
V_{RRM}	Repetitive peak reverse voltage(Tj =25 $^{\circ}\text{C}$)		600/800/1200/1600	V
V_{DSM}	Non repetitive surge peak Off-state voltage		$V_{DRM} + 100$	V
V_{RSM}	Non repetitive peak reverse voltage		$V_{RRM} + 100$	V
I^2t	I^2t value for fusing tp = 10 ms		880	A ² s
dI/dt	Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)		50	A/ μs

I_{GM}	Peak gate current	4	A
P_{G(AV)}	Average gate power dissipation	1	W
P_{GM}	Peak gate power	10	W

Electrical Characteristics : (T_j=25°C unless otherwise specified)

Symbol	Test Condition	Quadrant	Range	Value	Unit
I_{GT}	V _D =12V R _L =33Ω	I-II-III	MAX	50	mA
V_{GT}		I-II-III	MAX	1.3	V
V_{GD}	V _D =V _{DRM} R _L =3.3kΩ T _j =125°C	I-II-III	MIN	0.2	V
I_L	I _G =1.2 I _{GT}	I-III	MAX	80	mA
		II		100	
I_H	I _{TM} = 100mA		MAX	60	mA
dV/dt	V _D =2/3V _{DRM} Gate Open T _j =125°C		MIN	1000	V/μs
(dV/dt)_c	Without snubber T _j =125°C		MIN	20	V/μs

Static Characteristics

Symbol	Parameter		Value(MAX)	Unit
V_{TM}	I _{TM} =60A tp= 380μs	T _j =25°C	1.55	V
I_{DRM} I_{RRM}	V _D =V _{DRM} , V _R =V _{RRM}	T _j =25°C	10	μ A mA
		T _j =125°C	5	

Thermal Resistances :

Symbol	Parameter		Value	Unit
R_{th(j-c)}	Junction to case for AC	TO-3P(Ins)	0.9	°C/W

Fig.1: Maximum power dissipation versus RMS on-state current

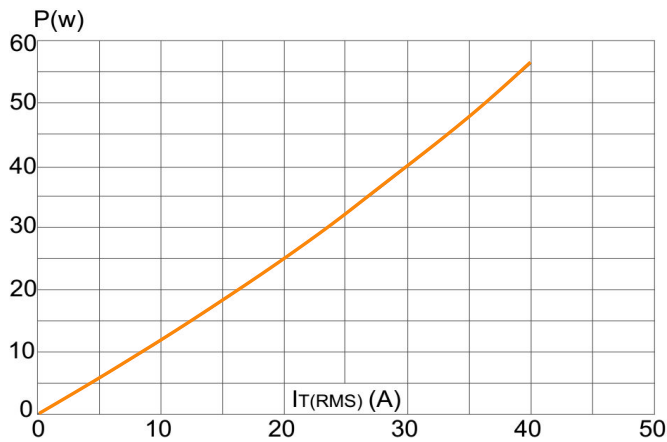


Fig.2 : RMS on-state current versus case temperature

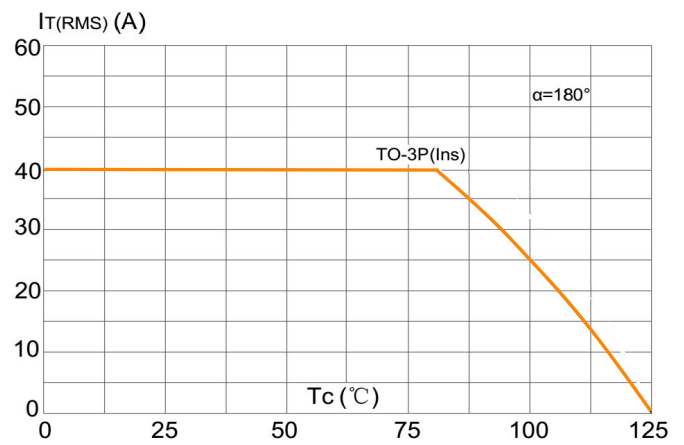


Fig.3 : Surge peak on-state current versus number of cycles

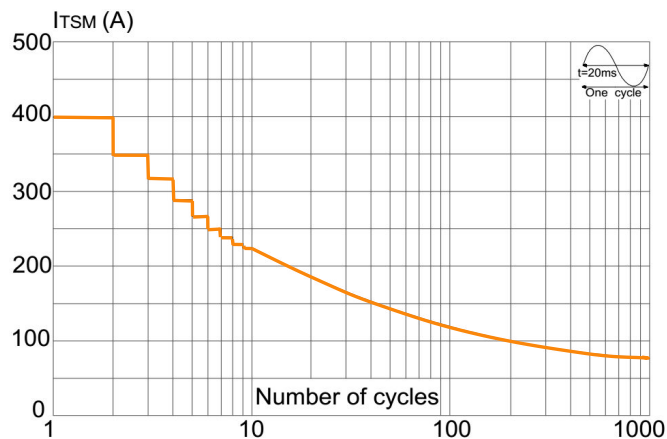


Fig.4 : On-state characteristics (maximum values)

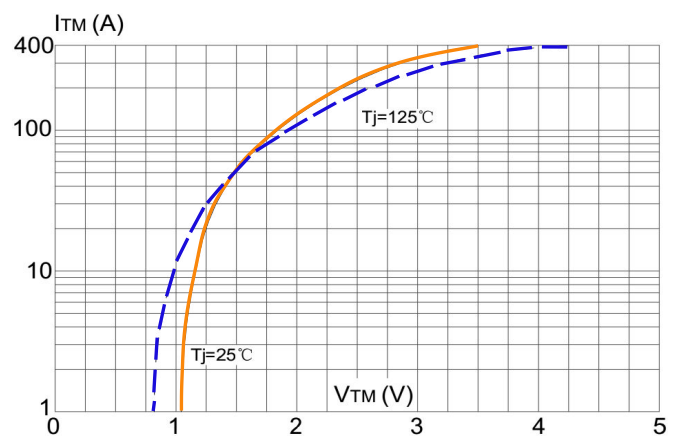


Fig.5 : Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$ and corresponding value of I_t ($dI/dt < 50A/\mu s$)

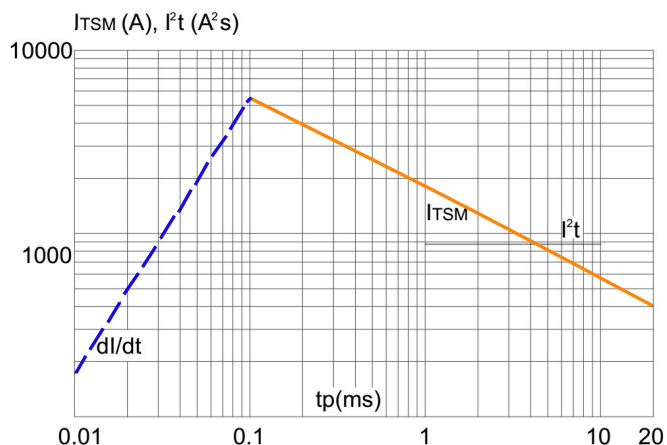
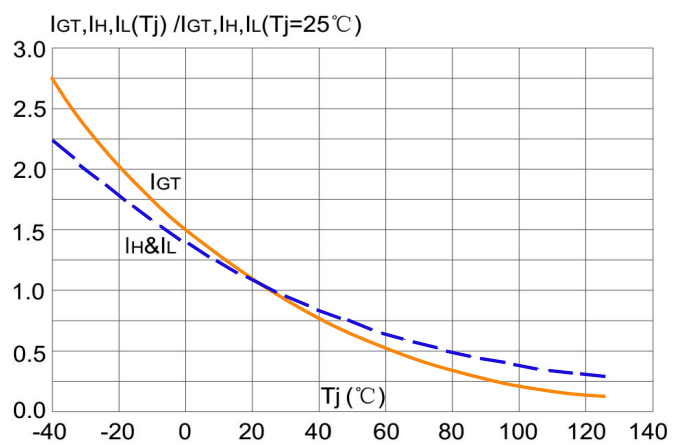


Fig.6: Relative variations of gate trigger current, holding current and latching current versus unjunction temperature



Ordering Information:

BT TRIAC SERIES A:insulated B:non-insulated	A	41 - 600	B IGT Class 600: $V_{DRM}/V_{RRM} \geq 600$ 800: $V_{DRM}/V_{RRM} \geq 800$ 1200: $V_{DRM}/V_{RRM} \geq 1200$ 1600: $V_{DRM}/V_{RRM} \geq 1600$
$I_{T(RMS)}: 40A$			

Package Mechanical Data :

